## AMENDMENT TO THE CLAIMS

The following listing of claims will replace all prior versions and listings of claims in the application.

(Currently Amended) Method for manufacturing a diamond film (8)—using a pulsed microwave plasma, in which, in a vacuum chamber–(1), a plasma (7)—of finite volume is formed near a substrate (5)—by subjecting a gas containing at least hydrogen and carbon to a pulsed discharge, which has a succession of low-power states and high-power states, and having a peak absorbed power P<sub>C</sub>, so as to obtain at least carbon-containing radicals in the plasma (7)—and to deposit the said carbon-containing radicals on the substrate (5)—in order to form a diamond film (8)—thereon;

characterized in that power is injected into the volume of the plasma with a peak power density of at least 100 W/cm³ while maintaining the substrate (5)-to a substrate temperature of between 700 °C and 1000 °C.

- 2. (<u>Currently Amended</u>) Method according to Claim 1, in which a plasma (<del>7)</del>-having at least one of the following features is generated near the substrate-(<del>5)</del>:
- the pulsed discharge has a certain peak absorbed power  $P_c$  and the ratio of the peak power to the volume of the plasma is between 100 W/cm<sup>3</sup> and 250 W/cm<sup>3</sup>,
  - the maximum temperature of the plasma is between 3500 K and 5000 K.
- the temperature of the plasma in a boundary region of the plasma located less than 1 cm from the surface of the substrate is between 1500 K and 3000 K and
- the plasma contains hydrogen atoms having a maximum concentration in the plasma of between  $1.7 \times 10^{16}$  and  $5 \times 10^{17}$  cm<sup>-3</sup>.
- 3. (Original) Method according to Claim 1 or Claim 2, in which said gas contains carbon and hydrogen in a carbon/hydrogen molar ratio of between 1% and 12%.
- 4. (Currently Amended) Method according to any one of the preceding claims Claim 1, in which said gas contains at least one hydro-carbon, and a plasma (7)-having a concentration of the carbon-containing radicals of between  $2 \times 10^{14}$  cm<sup>-3</sup> and  $1 \times 10^{15}$  cm<sup>-3</sup> is generated.

- 5. (Currently Amended) Method according to any one of the preceding claims Claim 1, in which a pulsed discharge is produced, in which the ratio of the duration of the high-power state to the duration of the low-power state is between 1/9 and 1.
- 6. (Currently Amended) Method according to any one of the preceding claims Claim 1, in which at least one of the following parameters is estimated:
  - a substrate temperature,
  - a temperature of the plasma,
- a temperature of the plasma in said boundary region, located less than 1 cm from the surface of the substrate.
  - a concentration of atomic hydrogen in the plasma,
  - a concentration of carbon-containing radicals in the plasma.
- a concentration of carbon-containing radicals in said boundary region close to the plasma,
  - a pressure of the plasma and
  - a power density of the plasma,

and the power emitted as a function of time is adapted according to at least one of these parameters.

- 7. (Currently Amended) Method according to any one of the preceding claims Claim 1, in which the plasma is contained in a cavity with at least one of the following properties:
  - the pulsed discharge has a peak power of at least 5 kW at 2.45 GHz.
  - the pressure of the plasma is between 100 mbar and 350 mbar and
- the gas containing hydrogen and carbon is emitted with a ration of the flow rate to the volume of plasma of between 0.75 and 7.5 sccm/cm³.
- 8. (<u>Currently Amended</u>) Method according to any one of <u>Claims 1 to 6 Claim 1</u>, in which the plasma is contained in a cavity with at least one of the following properties:
  - the pulsed discharge has a peak power of at least 10 kW at 915 MHz,
  - the pressure of the plasma is between 100 mbar and 350 mbar and
- the gas containing hydrogen and carbon is emitted with a ratio of the flow rate to the volume of the plasma of between 0.75 and 7.5 sccm/cm<sup>3</sup>.